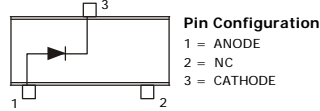
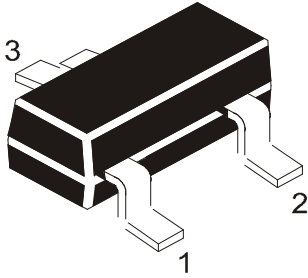


SILICON PLANAR SCHOTTKY DIODES

BAT54



SOT-23
Formed SMD Package
 For Lead Free Parts, Device Part #
 will be Prefixed with "T"

Marking
 BAT54 =L4

Ultra High Speed Switching Diodes

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNIT
Repetitive Peak Reverse Voltage	V_{RRM}	30	V
Forward Current (DC)	I_F	200	mA
Repetitive Peak Forward Current	I_{FRM}	300	mA
Non Repetitive Peak Forward Current $t < 1s$	I_{FSM}	600	mA
Power Dissipation $T_a = 25^\circ C$	P_D	230	mW
Storage Temperature Range	T_{stg}	- 55 to +150	$^\circ C$
Junction Temperature	T_j	125	$^\circ C$

THERMAL RESISTANCE

Junction to Ambient in free air	$R_{th(j-a)}$	430	K/W
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ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ C$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Forward Voltage	V_F	$I_F = 0.1mA$		0.24	V
		* $I_F = 1mA$		0.32	V
		$I_F = 10mA$		0.40	V
		* $I_F = 30mA$		0.50	V
		$I_F = 100mA$		1.00	V
Reverse Current	I_R	$V_R = 25V$		2.0	μA
Reverse Breakdown Voltage	$V_{(BR)R}$	$I_R = 100\mu A$	30		V

DYNAMIC CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Diode Capacitance	C_d	$V_R = 1V, f = 1MHz$		15	pF
Reverse Recovery Time When Switched From	t_{rr}	$I_F = 10mA$ to $I_R = 10mA$, measured at $I_R = 1mA$, $R_L = 100\Omega$		5	ns

*Temperature coefficient of forward voltage

- 0.6 %K at $I_F = 1mA$

- 0.3 %K at $I_F = 30mA$

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
SOT-23 T&R	3K/reel	136 gm/3K pcs	3" x 7.5" x 7.5"	12.0K	17" x 15" x 13.5"	192.0K	12 kgs
			9" x 9" x 9"	51.0K	19" x 19" x 19"	408.0K	28 kgs
	10K/reel	415 gm/10K pcs	13" x 13" x 0.5"	10.0K	17" x 15" x 13.5"	300.0K	16 kgs

Customer Notes

Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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